

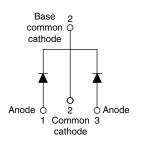
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Vishay Semiconductors

# High Performance Schottky Rectifier, 2 x 10 A



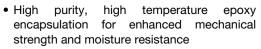
**TO-220AB** 



PRODUCT SUMMARY							
I <sub>F(AV)</sub>	2 x 10 A						
$V_{R}$	35 V, 45 V						
V <sub>F</sub> at I <sub>F</sub>	0.57 V						
I <sub>RM</sub> max.	15 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
E <sub>AS</sub>	8 mJ						
Package	TO-220AB						
Diode variation	Common cathode						

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	A						
V <sub>RRM</sub>		35/45	V						
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C (per leg)	20	Δ.						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	Α						
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V						
TJ	Range	-65 to 150	°C						

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-MBR2035CTHN3 VS-MBR2045CTHN3 UNITS							
Maximum DC reverse voltage	$V_R$	35	45	V			
Maximum working peak reverse voltage	$V_{RWM}$	33	45				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS			
Maximum average per leg	1	$T_C = 135 ^{\circ}\text{C}$ , rated $V_B$		10				
forward current per device	I <sub>F(AV)</sub>	$r_C = 135$ C, rated $v_R$		20				
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20	kHz, T <sub>C</sub> = 135 °C	20				
Non-repetitive peak surge current	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	А			
		Surge applied at rated load condition half wave, single phase, 60 Hz		150				
Repetitive avalanche current per leg I <sub>AR</sub>		Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		2				
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25 ^{\circ}\text{C},  I_{AS} = 2  \text{A},  L = 4  \text{mH}$		8	mJ			



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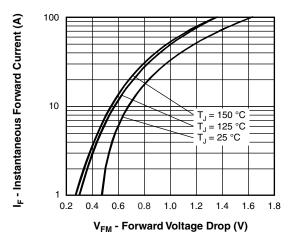
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		20 A	T <sub>J</sub> = 25 °C	0.84				
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	T. <sub>1</sub> = 125 °C	0.57	V			
		20 A	1J = 125 C	0.72				
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.1	- mA			
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C	hated DC voltage	15				
Threshold voltage	V <sub>F(TO)</sub>	T - T movimum		0.354	V			
Forward slope resistance r <sub>t</sub>		$T_J = T_J$ maximum		17.6	mΩ			
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	600	pF				
Typical series inductance	L <sub>S</sub>	Measured from top of term	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

#### Note

 $^{(1)}\,$  Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temper	rature range	TJ		-65 to 150	°C		
Maximum storage temper	ature range	$T_{Stg}$		-65 to 175			
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	2.0	°C/W		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased (only for TO-220)	0.50			
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting toward	minimum		Non-lubricated threads	6 (5)	kgf · cm		
Mounting torque	maximum		Non-lubricated trireads	12 (10)	(lbf · in)		
Marking device			Coop of the TO 200AP	MBR2035CTH			
			Case style TO-220AB	MBR2045CTH			





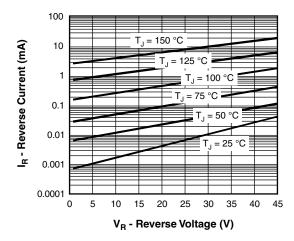


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

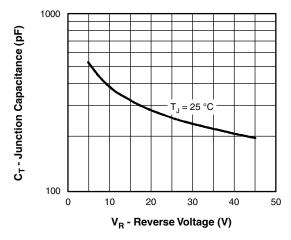


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

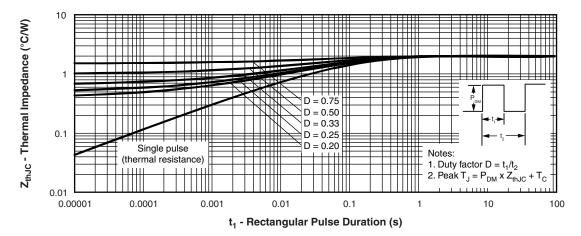


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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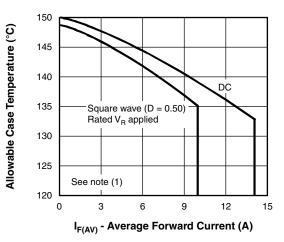


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

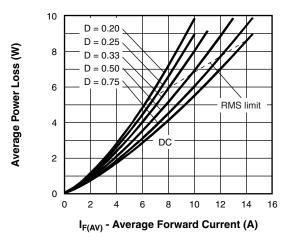


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

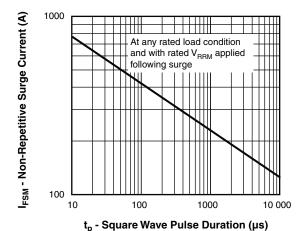


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

### Note

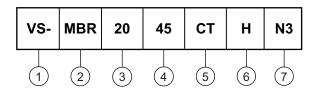
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 



## Vishay Semiconductors

### **ORDERING INFORMATION TABLE**





Vishay Semiconductors product

2 - Schottky MBR series

3 - Current rating (20 = 20 A)

35 = 35 V 45 = 45 V

5 - CT = Essential part number

6 - H = AEC-Q101 qualified

7 - Environmental digit

• N3 = Halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MBR2035CTHN3	50	1000	Antistatic plastic tube					
VS-MBR2045CTHN3	50	1000	Antistatic plastic tube					

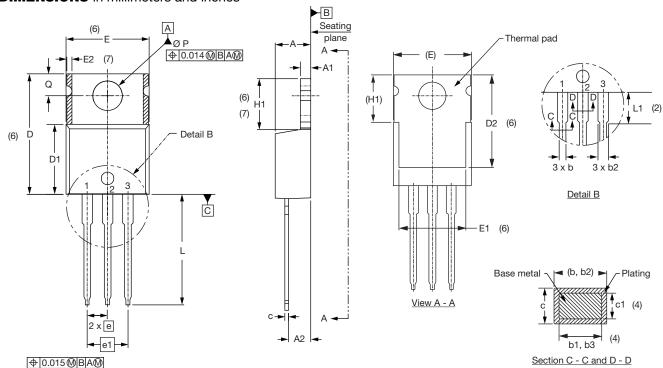
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95222						
Part marking information TO-220AB-N3	www.vishay.com/doc?95028						
SPICE model	www.vishay.com/doc?95295						

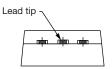


## Vishay Semiconductors

### **TO-220AB**

### **DIMENSIONS** in millimeters and inches





### Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			E	10.11	10.51	0.398	0.414	3, 6
A1	1.14	1.40	0.045	0.055			E1	6.86	8.89	0.270	0.350	6
A2	2.56	2.92	0.101	0.115			E2	ı	0.76	1	0.030	7
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	5.84	6.86	0.230	0.270	6, 7
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.73	0.139	0.147	
D	14.85	15.25	0.585	0.600	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355			θ	90° t	o 93°	90° t	o 93°	
D2	11.68	12.88	0.460	0.507	6			•		•	•	•

#### **Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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